## PMP20771 REV B Bill of Materials



PCB C1, C2 C3 C4 C5, C6 C7 C8, C9, C10 C11 C14 C15 D1 D2 D3 D4 D5 F1	1 0 1 0 2 8 1 2 3 1 1 2 1 0 1 2 1 6 1 2 1 6 1 4 1 1	Value  22uF  0.047uF  0.1uF  320uF  220uF  1uF  2200pF  0.47uF  2200pF  300V  300V  40V	PartNumber PMP20771 EEU-EE2E220 GRM32DR72J473KW01L B32520C3104K289 RL80J821MDN1KX UKA1A221MED1TD GRM188R71E105KA12D GRM1885C1H222JA01D GRM21BR71H474KA88L DE1E3KX222MA5BA01 Z4DGP406L-HF SMCJ200A MURA160T3G PDS340	Manufacturer  Any Panasonic MuRata TDK Nichicon Nichicon MuRata MuRata MuRata MuRata MuRata Comchip Technology Littlefuse ON Semiconductor	Printed Circuit Board  CAP, AL, 22 μF, 250 V, +/- 20%, TH  CAP, CERM, 0.047 μF, 630 V, +/- 10%, X7R, 1210  CAP, Film, 0.1 μF, 250 V, +/- 10%, TH  CAP, AL, 820 μF, 6.3 V, +/- 20%, 0.008 ohm, TH  CAP, AL, 220 μF, 10 V, +/- 20%, TH  CAP, CERM, 1 μF, 25 V, +/- 10%, X7R, 0603  CAP, CERM, 2200 pF, 50 V, +/- 5%, C0G/NP0, 0603  CAP, CERM, 0.47 μF, 50 V, +/- 10%, X7R, 0805  CAP, CERM, 2200 pF, 250 V, +/- 20%, E, Disc 10x8mm  Diode, P-N-Bridge, 600 V, 4 A, Z4-D	PackageReference  Cap, 10x20mm 1210 10x4x8.5mm D8xL8 D6.3xL11mm 0603 0603 0805 Disc 10x8mm Z4-D
C1, C2 C3 C4 C5, C6 C7 C8, C9, C10 C11 C14 C15 D1 D2 D3 D4 D5 F1	1 0 1 0 2 8 1 2 3 1 1 2 1 0 1 2 1 6 1 2 1 6 1 4 1 1	0.047uF 0.1uF 0.1uF 0.20uF 0.220uF 0.47uF 0.2200pF 0.00V 0.00V	EEU-EE2E220 GRM32DR72J473KW01L B32520C3104K289 RL80J821MDN1KX UKA1A221MED1TD GRM188R71E105KA12D GRM1885C1H222JA01D GRM21BR71H474KA88L DE1E3KX222MA5BA01 Z4DGP406L-HF SMCJ200A MURA160T3G	Panasonic  MuRata  TDK  Nichicon  Nichicon  MuRata  MuRata  MuRata  MuRata  MuRata  MuRata  Comchip Technology  Littlefuse	CAP, AL, 22 μF, 250 V, +/- 20%, TH  CAP, CERM, 0.047 μF, 630 V, +/- 10%, X7R, 1210  CAP, Film, 0.1 μF, 250 V, +/- 10%, TH  CAP, AL, 820 μF, 6.3 V, +/- 20%, 0.008 ohm, TH  CAP, AL, 220 μF, 10 V, +/- 20%, TH  CAP, CERM, 1 μF, 25 V, +/- 10%, X7R, 0603  CAP, CERM, 2200 pF, 50 V, +/- 5%, C0G/NP0, 0603  CAP, CERM, 0.47 μF, 50 V, +/- 10%, X7R, 0805  CAP, CERM, 2200 pF, 250 V, +/- 20%, E, Disc 10x8mm  Diode, P-N-Bridge, 600 V, 4 A, Z4-D	1210 10x4x8.5mm D8xL8 D6.3xL11mm 0603 0603 0805 Disc 10x8mm Z4-D
C3 C4 C5, C6 C7 C8, C9, C10 C11 C14 C15 D1 D2 D3 D4 D5 F1	1 0 1 0 2 8 1 2 3 1 1 2 1 0 1 2 1 6 1 2 1 6 1 4 1 1	0.047uF 0.1uF 0.1uF 0.20uF 0.220uF 0.47uF 0.2200pF 0.00V 0.00V	GRM32DR72J473KW01L B32520C3104K289 RL80J821MDN1KX UKA1A221MED1TD GRM188R71E105KA12D GRM1885C1H222JA01D GRM21BR71H474KA88L DE1E3KX222MA5BA01 Z4DGP406L-HF SMCJ200A MURA160T3G	MuRata TDK Nichicon Nichicon MuRata MuRata MuRata MuRata MuRata Comchip Technology Littlefuse	CAP, CERM, 0.047 μF, 630 V, +/- 10%, X7R, 1210  CAP, Film, 0.1 μF, 250 V, +/- 10%, TH  CAP, AL, 820 μF, 6.3 V, +/- 20%, 0.008 ohm, TH  CAP, AL, 220 μF, 10 V, +/- 20%, TH  CAP, CERM, 1 μF, 25 V, +/- 10%, X7R, 0603  CAP, CERM, 2200 pF, 50 V, +/- 5%, C0G/NP0, 0603  CAP, CERM, 0.47 μF, 50 V, +/- 10%, X7R, 0805  CAP, CERM, 2200 pF, 250 V, +/- 20%, E, Disc 10x8mm  Diode, P-N-Bridge, 600 V, 4 A, Z4-D	1210 10x4x8.5mm D8xL8 D6.3xL11mm 0603 0603 0805 Disc 10x8mm Z4-D
C4 C5, C6 C7 C8, C9, C10 C11 C14 C15 D1 D2 D3 D4 D5 F1	1 0 2 8 1 2 3 1 1 2 1 0 1 2 1 6 1 2 1 6 1 4 1 1	0.1uF 820uF 820uF 1uF 82200pF 0.47uF 8200pF 800V 800V 800V	B32520C3104K289 RL80J821MDN1KX UKA1A221MED1TD GRM188R71E105KA12D GRM1885C1H222JA01D GRM21BR71H474KA88L DE1E3KX222MA5BA01 Z4DGP406L-HF SMCJ200A MURA160T3G	TDK Nichicon Nichicon MuRata MuRata MuRata MuRata MuRata Comchip Technology Littlefuse	CAP, Film, 0.1 μF, 250 V, +/- 10%, TH  CAP, AL, 820 μF, 6.3 V, +/- 20%, 0.008 ohm, TH  CAP, AL, 220 μF, 10 V, +/- 20%, TH  CAP, CERM, 1 μF, 25 V, +/- 10%, X7R, 0603  CAP, CERM, 2200 pF, 50 V, +/- 5%, C0G/NP0, 0603  CAP, CERM, 0.47 μF, 50 V, +/- 10%, X7R, 0805  CAP, CERM, 2200 pF, 250 V, +/- 20%, E, Disc 10x8mm  Diode, P-N-Bridge, 600 V, 4 A, Z4-D	10x4x8.5mm D8xL8 D6.3xL11mm 0603 0603 0805 Disc 10x8mm Z4-D
C5, C6 C7 C8, C9, C10 C11 C14 C15 D1 D2 D3 D4 D5 F1	2 8 1 2 3 1 1 2 1 0 1 2 1 6 1 2 1 6 1 4 1 1	320uF 220uF 1uF 2200pF 0.47uF 2200pF 500V 200V 500V	RL80J821MDN1KX UKA1A221MED1TD GRM188R71E105KA12D GRM1885C1H222JA01D GRM21BR71H474KA88L DE1E3KX222MA5BA01 Z4DGP406L-HF SMCJ200A MURA160T3G	Nichicon Nichicon MuRata MuRata MuRata MuRata MuRata Comchip Technology Littlefuse	CAP, AL, 820 μF, 6.3 V, +/- 20%, 0.008 ohm, TH  CAP, AL, 220 μF, 10 V, +/- 20%, TH  CAP, CERM, 1 μF, 25 V, +/- 10%, X7R, 0603  CAP, CERM, 2200 pF, 50 V, +/- 5%, C0G/NP0, 0603  CAP, CERM, 0.47 μF, 50 V, +/- 10%, X7R, 0805  CAP, CERM, 2200 pF, 250 V, +/- 20%, E, Disc 10x8mm  Diode, P-N-Bridge, 600 V, 4 A, Z4-D	D8xL8 D6.3xL11mm 0603 0603 0805 Disc 10x8mm Z4-D
C7 C8, C9, C10 C11 C14 C15 D1 D2 D3 D4 D5 F1	1 2 3 1 1 2 1 0 1 2 1 6 1 2 1 6 1 4 1 1	220uF luF 2200pF 0.47uF 2200pF 500V 200V 500V	UKA1A221MED1TD GRM188R71E105KA12D GRM1885C1H222JA01D GRM21BR71H474KA88L DE1E3KX222MA5BA01 Z4DGP406L-HF SMCJ200A MURA160T3G	Nichicon MuRata MuRata MuRata MuRata MuRata Comchip Technology Littlefuse	CAP, AL, 220 μF, 10 V, +/- 20%, TH  CAP, CERM, 1 μF, 25 V, +/- 10%, X7R, 0603  CAP, CERM, 2200 pF, 50 V, +/- 5%, C0G/NP0, 0603  CAP, CERM, 0.47 μF, 50 V, +/- 10%, X7R, 0805  CAP, CERM, 2200 pF, 250 V, +/- 20%, E, Disc 10x8mm  Diode, P-N-Bridge, 600 V, 4 A, Z4-D	D6.3xL11mm 0603 0603 0805 Disc 10x8mm Z4-D
C8, C9, C10 C11 C14 C15 D1 D2 D3 D4 D5 F1	3 1 1 2 1 0 1 2 1 6 1 2 1 6 1 4 1 1 1 1	2200pF 2200pF 2200pF 2200pF 600V 200V 600V	GRM188R71E105KA12D GRM1885C1H222JA01D GRM21BR71H474KA88L DE1E3KX222MA5BA01 Z4DGP406L-HF SMCJ200A MURA160T3G	MuRata MuRata MuRata MuRata MuRata Comchip Technology Littlefuse	CAP, CERM, 1 μF, 25 V, +/- 10%, X7R, 0603  CAP, CERM, 2200 pF, 50 V, +/- 5%, C0G/NP0, 0603  CAP, CERM, 0.47 μF, 50 V, +/- 10%, X7R, 0805  CAP, CERM, 2200 pF, 250 V, +/- 20%, E, Disc 10x8mm  Diode, P-N-Bridge, 600 V, 4 A, Z4-D	0603 0603 0805 Disc 10x8mm Z4-D
C11 C14 C15 D1 D2 D3 D4 D5 F1	1 2 1 0 1 2 1 6 1 2 1 6 1 4 1 1 1 1	2200pF 0.47uF 2200pF 600V 200V 600V	GRM1885C1H222JA01D GRM21BR71H474KA88L DE1E3KX222MA5BA01 Z4DGP406L-HF SMCJ200A MURA160T3G	MuRata MuRata MuRata Comchip Technology Littlefuse	CAP, CERM, 2200 pF, 50 V, +/- 5%, C0G/NP0, 0603 CAP, CERM, 0.47 μF, 50 V, +/- 10%, X7R, 0805 CAP, CERM, 2200 pF, 250 V, +/- 20%, E, Disc 10x8mm Diode, P-N-Bridge, 600 V, 4 A, Z4-D	0603 0805 Disc 10x8mm Z4-D
C14 C15 D1 D2 D3 D4 D5 F1	1 0 1 2 1 6 1 2 1 6 1 4 1 1 1 1	0.47uF 2200pF 600V 200V 600V	GRM21BR71H474KA88L DE1E3KX222MA5BA01 Z4DGP406L-HF SMCJ200A MURA160T3G	MuRata MuRata Comchip Technology Littlefuse	CAP, CERM, 0.47 μF, 50 V, +/- 10%, X7R, 0805 CAP, CERM, 2200 pF, 250 V, +/- 20%, E, Disc 10x8mm Diode, P-N-Bridge, 600 V, 4 A, Z4-D	0805 Disc 10x8mm Z4-D
C15 D1 D2 D3 D4 D5 F1	1 2 1 6 1 2 1 6 1 4 1 1 1 1	2200pF 500V 200V 500V	DE1E3KX222MA5BA01 Z4DGP406L-HF SMCJ200A MURA160T3G	MuRata Comchip Technology Littlefuse	CAP, CERM, 2200 pF, 250 V, +/- 20%, E, Disc 10x8mm Diode, P-N-Bridge, 600 V, 4 A, Z4-D	Disc 10x8mm Z4-D
D1	1 6 1 2 1 6 1 4 1 1 1	600V 200V 600V	Z4DGP406L-HF SMCJ200A MURA160T3G	Comchip Technology Littlefuse	Diode, P-N-Bridge, 600 V, 4 A, Z4-D	Z4-D
D2 D3 D4 D5 F1	1 2 1 6 1 4 1 1 1	200V 600V 40V	SMCJ200A MURA160T3G	Littlefuse		
D3	1 6 1 4 1 1 1 1	V00V 10V	MURA160T3G			SMC
D4	1 4 1 1 1 1	10V			TVS DIODE 200VWM 324VC SMC Diode, Ultrafast, 600 V, 1 A, SMA	SMA
D5 -	1 1 1 1		IPD5340			
F1	1	100 V	MMDL914-TP	Diodes Inc.	Diode, Schottky, 40 V, 3 A, PowerDI5	PowerDI5
	1			-	nen Diode, Switching, 100 V, 0.2 A, SOD-323	SOD-323
J1 -	'		0452003.MRL	Littelfuse	Fuse, 3 A, 125VAC/VDC, SMD	SloBlo452
			1-1318301-2	TE Connectivity	Polarized Header, 7.92 mm, 2x1, Tin, TH	TH Header
= -		33uH	NR6028T330M	Taiyo Yuden	Inductor, Wirewound, Ferrite, 33 µH, 1.1 A, 0.22 ohm, SMD	6.0x2.8x6.0mm
L2	1 4	170nH	SPM6530T-R47M170	TDK	Inductor, Shielded, Ferrite, 470 nH, 15.7 A, 0.0036 ohm, SMD	SMD 7.1x3.0x6.5mm
L3	1 6	600uH	UU9.8V-601LF	GCI Technologies	Coupled inductor, 600 µH, 1 A, 0.2 ohm, TH	Coupled inductor, 17.5x17x11mm
Q2	1 3	30V	CSD17559Q5	Texas Instruments	MOSFET, N-CH, 30 V, 100 A, DQH0008A (VSON-CLIP-8)	DQH0008A
		350V	IPD60R380C6ATMA1	Infineon Technologies	MOSFET, N-CH, 650 V, 10.6 A, DPAK	DPAK
		1.00	CRCW08051R00FKEA	Vishay-Dale	RES, 1.00, 1%, 0.125 W, 0805	0805
	1 2	232k	CRCW0402232KFKED	Vishay-Dale	RES, 232 k, 1%, 0.063 W, 0402	0402
	1 0		CRCW06030000Z0EA	Vishay-Dale	RES, 0, 5%, 0.1 W, 0603	0603
	1 1	150k	CRCW0402150KFKED	Vishay-Dale	RES, 150 k, 1%, 0.063 W, 0402	0402
		28.7k	CRCW040228K7FKED	Vishay-Dale	RES, 28.7 k, 1%, 0.063 W, 0402	0402
		10.0k	CRCW040210K0FKED	Vishay-Dale	RES, 10.0 k, 1%, 0.063 W, 0402	0402
		6.5k	CRCW040266K5FKED	Vishay-Dale	RES, 66.5 k, 1%, 0.063 W, 0402	0402
		1.7	CRCW12064R70JNEA	Vishay-Dale	RES, 4.7, 5%, 0.25 W, 1206	1206
		37.4k	CRCW040237K4FKED	Vishay-Dale	RES, 37.4 k, 1%, 0.063 W, 0402	0402
		20.0k	CRCW040220K0FKED	Vishay-Dale	RES, 20.0 k, 1%, 0.063 W, 0402	0402
		199	CRCW0402499RFKED	Vishay-Dale	RES, 499, 1%, 0.063 W, 0402	0402
		2.0Meg	CRCW12062M00JNEA	Vishay-Dale	RES, 2.0 M, 5%, 0.25 W, 1206	1206
		1.00k	CRCW06031K00FKEA	Vishay-Dale	RES, 1.00 k, 1%, 0.1 W, 0603	0603
		300uH	RLTI-1222	Renco Electronics	Transformer, 300 uH, TH	870x830mil
		Red	5010	Keystone	Test Point, Multipurpose, Red, TH	Red Multipurpose Testpoint
TP2	1 E	Black	5011	Keystone	Test Point, Multipurpose, Black, TH	Black Multipurpose Testpoint
U1	1		UCC24636DBVR	Texas Instruments	Synchronous Rectifier Controller With Ultra-Low Standby Current, DBV0006A (SOT-6)	DBV0006A
U2	1		UCC28704DBVR-1	Texas Instruments	Off-Line Constant-Voltage Constant-Current Flyback Controller With Primary-Side Regulation (PSR), DBV0006A (SOT-6)	DBV0006A
Q4 (	0 6	650V	IPL60R299CP	Infineon Technologies	MOSFET, N-CH, 650 V, 11.1 A, PG-VSON-4	PG-VSON-4

Designator	Quantity	Value	PartNumber	Manufacturer	Description	PackageReference
R1, R2	. ()	0	CRCW12060000Z0EA	Vishay-Dale	RES, 0, 5%, 0.25 W, 1206	1206

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